

Development status of the LAUE project

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In collaboration with:

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Outline

- ▶ Introduction;
- ▶ Laue Lenses principles;
- ▶ The LAUE project;
- ▶ The LARIX facility;
- ▶ Selected crystals and petal properties;
- ▶ Performances simulations;
- ▶ Conclusion.

The 80-600 keV range is crucial for several scientific objectives

- ▶ Physics of NS in presence of super-strong magnetic fields (Mass accreting X-ray pulsars, Anomalous X-ray Pulsars);
- ▶ Nuclear lines (e.g., ^{44}Ti) produced in SN explosions.

Introduction

Many open issues are expected to be solved with focusing telescopes that cover the soft gamma-ray band (> 80 keV)

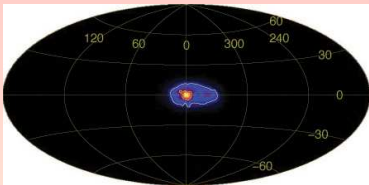


Figure: INTEGRAL map of the glow of 511 keV gamma-rays from electron-positron annihilation (Weidenspointner et al., 2008)

One of the most elusive questions is the origin of positrons in the Galactic Center (CG) region. Is it due to:

- hard low mass X-ray binaries, strong emitters of hard X-rays (>20 keV)?
- extended region of antimatter or dark matter?
- existence of a source of radioactive elements like ^{26}Al , ^{56}Co , ^{44}Ti ?
- presence of a gamma-ray source (e.g., gamma-ray pulsar)?

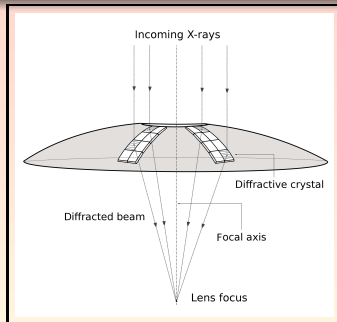
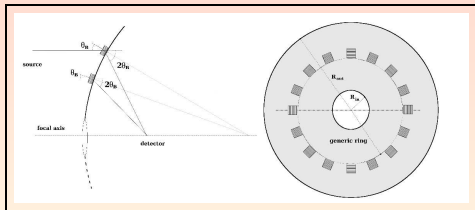
Laue lens principles

The Bragg Law

$$2d_{hkl} \sin\theta_B = n \frac{\hbar c}{E_B}$$

Energy–radius relation:

$$E_B \approx \frac{\hbar c f}{d_{hkl} R_{ring}}$$



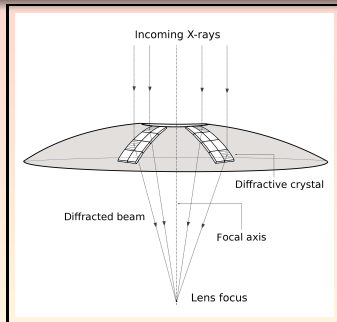
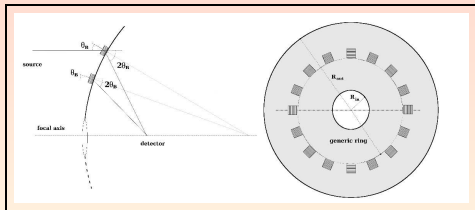
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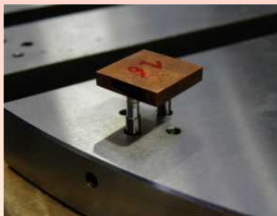
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From the HAXTEL to the LAUE project

In the HAXTEL project 3 phases were used for positioning each crystal:

- ▶ gluing pins as references for the diffractive planes;
- ▶ positioning in a drilled countermask;
- ▶ gluing the set of crystals on the carbon fiber support.



Limitations

- Time consuming;
- Limited accuracy due to the multi-phase process;
- Satisfactory for short focal length Laue lenses (<10 m).

The LAUE project

The main objective: a focusing lens for hard X-/soft γ -rays 80 – 600 keV

Goals of the LAUE project

- ▶ **Massive production of crystals** for diffraction, in a relatively short time, with high efficiency and desired spread (15÷25 arcsec);
- ▶ **Technology for assembly a large number of crystals:** accuracy better than 10 arcsec;
- ▶ **Facility for assembling the crystals** on a petal with the required accuracy and for the performance tests;
- ▶ **Realization of a petal** using the selected crystals.

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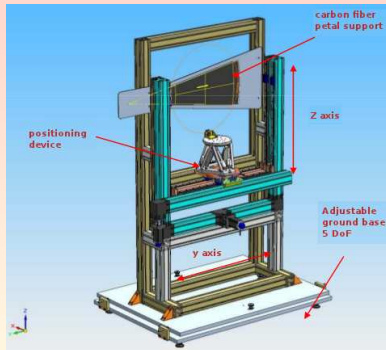
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The LAUE project: a lens for X and γ -rays

How to assemble hundreds of crystals?

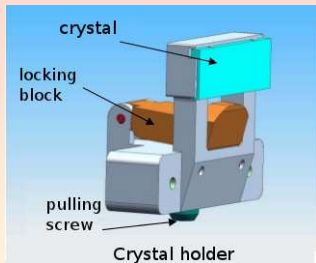
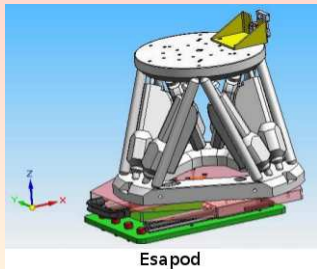
In the LAUE project the crystals will be directly placed on a carbon fiber support using a mechanical device (**DTM Technologies – Modena (Italy)**)



The LAUE project: a lens for X and γ -rays

How to assemble hundreds of crystals?

Two positioner were developed to set each crystal on the petal frame. A **coarse positioner** made of two perpendicular y/z translation stages. A **fine positioner (esapod)** accurately control the crystal tilting around two perpendicular axes and its motion toward the frame.



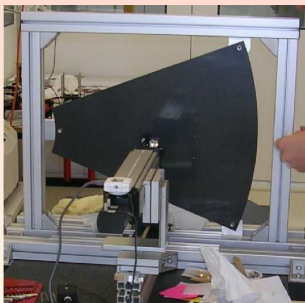
A crystal holder holds the crystal in such a way that four out of six faces are kept free (for the beam incidence and for positioning the tiles side by side).

The LAUE project: a lens for X and γ -rays

How to assemble hundreds of crystals?

Advantages

- Faster alignment;
- Expected accuracy 10 times better than in the HAXTEL method (~ 10 arcsec).



The LAUE project

A focusing lens for hard X-/soft γ -rays 70 – 600 keV

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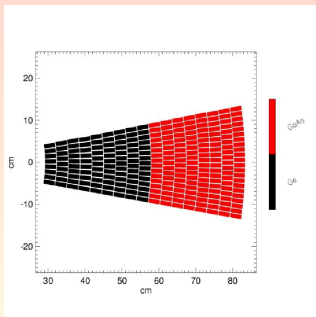
The LAUE project

Building a petal

Petal properties

On the basis of:

- Available X-ray source (< 320 keV);
- Beam-line dimension.



Petal properties

Materials	Germanium (111) Gallium Arsenide (111)
Passband	80–300 keV
Focal Length	20 m
Crystal size	$30 \times 10 \times 2$ mm ³
N^o crystals	~ 300 (aperture angle 18°)
N^o rings	18

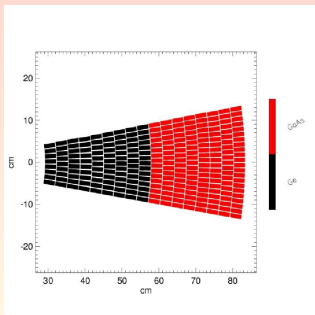
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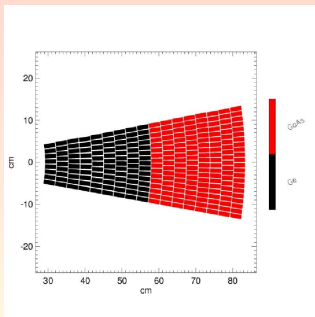
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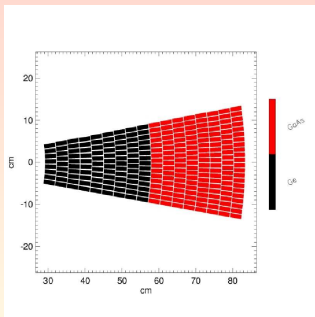
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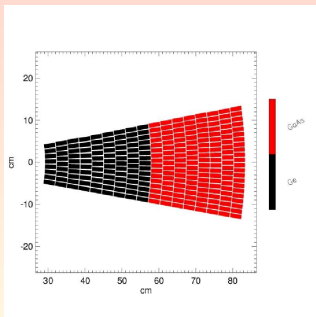
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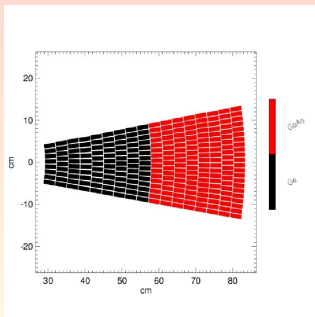
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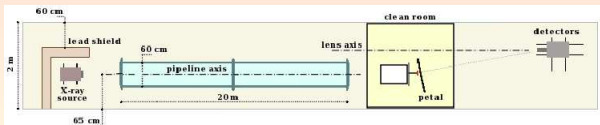
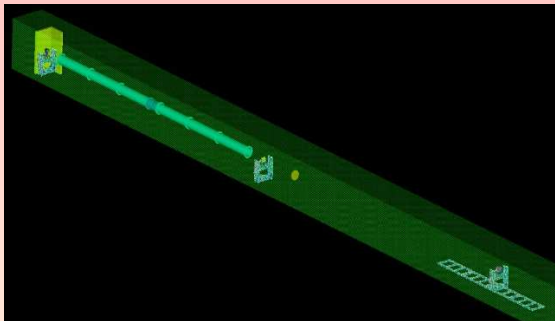
The LAUE project

A focusing lens for hard X-/soft γ -rays 70 – 600 keV

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The LARIX facility

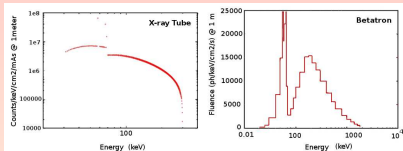


Source and **Collimator** are moved together along Y and Z axis providing a parallel X-ray beam to the target with a precision of ± 0.1 mm (few arcsec @ 20 m).

The LARIX facility

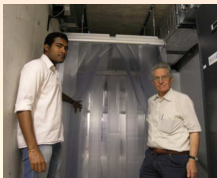
Photon source

X-ray tube up to ~ 320 keV (for building)
Bethatron source up to 2.5 MeV (for testing)



Clean room

Class 10⁵, humidity stable 50%, temperature ± 1 °C



Detectors

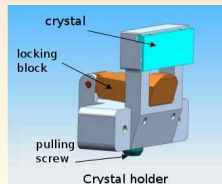
- Cooled HPGe (2.5 cm diameter) spectral resolution: 500 eV @ 122keV
- Imager (20 × 20 cm²) spatial resolution: 200 μ m

Energy range	20 keV - 15 MeV
Detector Sizes (cm):	29.5 × 36.0 × 2.2
Pixel pitch (μ m)	200
Pixel Matrix	1024x1024
Detector	HPGe
Energy range	3 keV - 1 MeV
Detector Size (mm):	200
Sensitive Depth (mm)	5-20
ΔE (FWHM) at 122 keV (eV)	480-610

The table lists technical specifications for two detectors. To the right of the table are two images: a large, rectangular, light-colored detector (likely the HPGe detector) and a smaller, cylindrical detector (likely the imager).

Robotic device

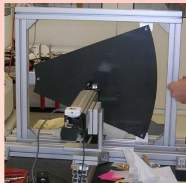
Mechanical holder for crystals alignment



The LARIX facility

Assembled/tested petal

Defined properties



Collimator

Slit collimator with four independent blades of W (20 mm thick), variable aperture and remote control



Beam-line

Vacuum environment (1–10 mbar)



Input–Output windows

Transparency: >90% @ 80 keV

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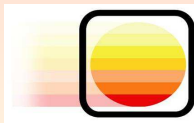
Crystal selection

Selected materials

- ▶ Ge(111) perfect (bent)
- ▶ GaAs(111) mosaic (bent)

Provided by:

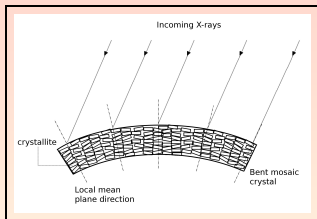
- Sensors and Semiconductors Laboratory (**LSS Ferrara**)
- Istituto dei Materiali per l' Elettronica ed il Magnetismo (**IMEM Parma**)



Crystals structure

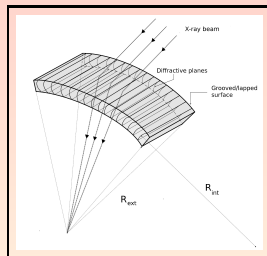
Bent mosaic and bent perfect crystals

The advantages of the bent crystals with respect to the flat ones lies in the focusing capability of each single tile. The PSF of flat mosaic crystals are limited by the dimension of the tiles.



Bent mosaic crystals

The direction of the mean plane of the crystallite gaussian distribution continuously changes along the crystal.



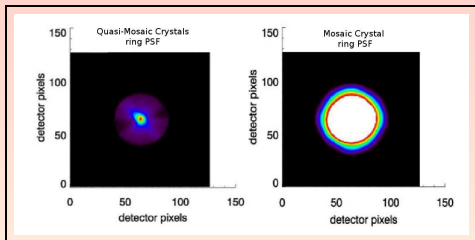
Bent perfect crystals

Surface indentations bending the tile under a certain R_{ext} , creates an internal secondary curvature, (R_{int}), which enhances the diffraction (**quasi-mosaic configuration**).

PSF simulation of a ring of crystals: ideal alignment

Quasi-mosaic crystals vs. flat mosaic crystals

Simulations with an uniform distribution of photons over each crystal in **one single ring** of the Lens @ 100 keV
Crystal size: $1.5 \times 1.5 \text{ cm}^2$
Thickness: 0.2 cm



Quasi-mosaic crystals

peak value $\sim 1.5 \times 10^5$

Flat mosaic crystals

peak value $\sim 1.2 \times 10^4$

Enclosed photons

50% @ 5.8 mm radius from the center of the PSF for mosaic crystals

50% @ 2.2 mm for quasi-mosaic crystals

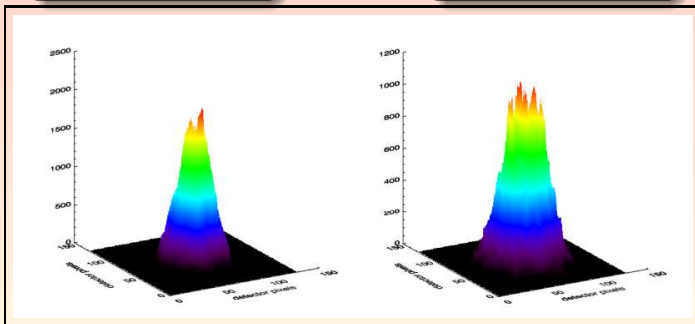
Misalignment effects

Crystal size: $1.5 \times 1.5 \text{ cm}^2$

With a gaussian distribution for the misalignments:

30 arcsec \rightarrow 1.3%

60 arcsec \rightarrow 0.8%



Technology for > 15 m FL is in the final developing stage (LAUE project):

- ▶ Defined a technology for a fast and accurate alignment of the crystals;
- ▶ Assembled a facility for build/test a petal;
- ▶ Acquired the know-how to align the crystals and build a petal;
- ▶ Performed a feasibility study for assembling a Laue lens made of petals.

Conclusions II

Crystal properties

- ▶ **Developed technology for the production of a large number of crystals suitable for Laue lenses;**
- ▶ Indented (bent) Germanium can be produced with the requested curvature radius (40 m);
- ▶ **Bent crystals improve angular resolution by an order of magnitude with respect to flat crystals;**
- ▶ Bent GaAs mosaic tiles can be produced with a mosaicity as defined by the project (20 – 30 arcsec) and with the requested reflectivity.

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